GH6C005B3A/GH6C005B3B GH6C005B5A/GH6C005B5B

Features

- (1) Easy mounting due to insert frame structure compared to conventional pin structure
- (2) Thin and compact package which enables to design thin and compact pick-up GH6C005B3A/B : 4.8mm thickness

GH6C005B5A/B: 3.0mm thickness

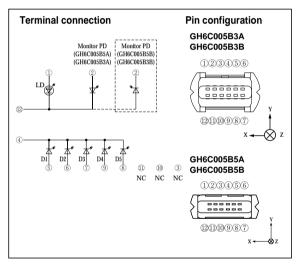
(3) With built-in beam splitter and diffraction grating

Model No.

- (1) GH6C005B3A/GH6C005B5A Dual power supply
- (2) GH6C005B3B/GH6C005B5BSingle power supply

Applications

- (1) Audio CD players
- (2) Video CD players



Absolute Maximum Ratings

	Param	eter	Symbol	Rating	Unit					
*1	Optical power output		Рн	4.3	mW					
		Laser		2	V					
	Reverse voltage	Monitor photodiode	VR	30	V					
		Signal detection photodiode		15	V					
*2	Operating temperation	ture	Topr	-10 to +70	°C					
*2	Storage temperature		Tstg	-40 to +85	°C					
**3	Soldering temperat	ure	Tsold	260	°C					

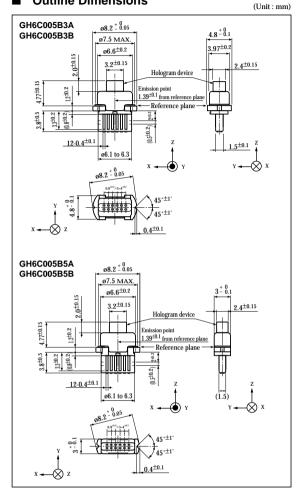
*1 Output power from hologram laser

*2 Case temperature

*3 At the position of 1.6mm or more from the lead base (Within 5s)

Compact Resin Stem Hologram Laser for Audio/Video CD Player

Outline Dimensions



(Tc=25°C)

SHARP

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64

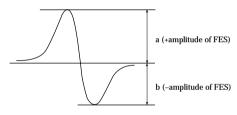
Electro-optical Characteristics

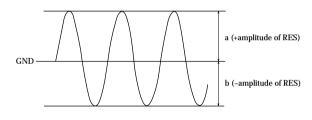
(Vcc=5V, Tc=25°C)

						(., ,
Par	ameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Focal offset		DEF	RF=6.0µA	-0.7	-	+0.7	μm
*2 Focal error sym	metry	BFES	RF=6.0µA	-25	-	+25	%
*3 Radial error bala	ance	Bres	P _H =3.0mW	-25	-	+25	%
*4 RF output ampli	itude	IRF	P _H =3.0mW	4.3	7.2	-	μΑ
*5 FES output amp	litude	IFES	RF=6.0µA	2.6	3.9	5.2	μΑ
*6 RES output amp	olitude	Ires	RF=6.0µA	0.7	1.1	1.5	μΑ
Threshold curre	ent	Ith	-	-	25	39	mA
Operating curre	ent	Iop	Рн=3.0mW	-	36	50	mA
Operating voltag	ge	Vop	Рн=3.0mW	-	1.75	2.20	V
Wavelength	Wavelength		P _H =3.0mW	770	780	795	nm
Outerstand	GH6C005B3A/GH6C005B5A	Im	P _H =3.0mW, V _R =15V	0.06	0.32	0.6	mA
Output current	GH6C005B3B/GH6C005B5B	Im		0.05	0.22	0.6	mA
Differential efficiency		ηd	2.0mW I(3.0mW)-I(1.0mW)	0.17	0.27	0.55	mW/mA

 $^{\oplus 1}~$ Distance between FES=0 and jitter minimum point At the condition of FES sensitivity = 20%/1µm

**2 (a-b) / (a+b)





- $^{\circledast 4}$ Amplitude of D2+D3+D4 (focal servo ON, radial servo ON)
- *5 D₂–D₃ (Focal vibration)

a-b

2×(a+b)

*3

*6 D1-D5 (focal servo ON, radial servo OFF)

 $(T_{C}=25^{\circ}C)$

(Tc=25°C)

Electro-optical Characteristics of Laser Diode (Design Standard)								
Symbol	Conditions	MIN.	TYP.	MAX.	Unit			
nission Symmetry Parallel S// Po=3mW, Into NA=0.11	-25	-	+25	%				
r S⊥	PO=3MW, INto INA=0.11	-15	-	+15	%			
$\Delta \mathbf{x}$	-	-80	-	+80	μm			
Δy		-80	-	+80	μm			
Δz		-80	-	+80	μm			
α	Po=3mW	-	-	0.99	-			
	Symbol S// r Δx Δy Δz	Symbol Conditions S// Po=3mW, Into NA=0.11 r S⊥ Δx Δy Δz $-$	SymbolConditionsMIN.S//Po=3mW, Into NA=0.11 -25 rS⊥ -15 Δx -80 Δy $ -80$ Δz -80	SymbolConditionsMIN.TYP.S//Po=3mW, Into NA=0.11 -25 $-$ rS⊥Po=3mW, Into NA=0.11 -15 $ \Delta x$ $ \Delta y$ $ \Delta z$ $ \Delta z$ $ -$	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			

Electrical Characteristics of Monitor Photodiode (Design Standard) (GH6C005B3A/GH6C005B5A)

- -

(
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Sensitivity	S	V _R =15V -	-	0.11	-	mA/mW
Dark current	ID		-	-	150	nA
Terminal capacitance	Ct	Vr=15V, f=1MHz	-	4.2	-	pF

(GH6C005B3B/GH6C005B5B)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Sensitivity	S	V _R =15V	-	0.07	-	mA/mW
Dark current	ID		-	-	150	nA
Terminal capacitance	Ct	VR=15V, f=1MHz	-	7.7	-	pF

*1 For hologram output power

■ Electro-optical Characteristics of Photodiode for Signal Detection (Design Standard) (Tc=25°C)

•				•		•	
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*2 Segment
Reverse voltage	Reverse voltage VR		15	-	150	V	A, B, C
Dark current	Dark current Id		-	-	10	nA	A, B, C
Wavelength	λ_p		-	800	-	nm	A, B, C
Terminal consoitence	Ct	V _R =15V. f=1MHz	1.2	-	5.0	pF	B, C
Terminal capacitance		VR=13V, I=1MHZ	1.4	-	5.8	pF	A
		Ev=1 000lx	130	210	-	nA	Α
*3 Short circuit current	Isc		50	80	-	nA	В
			70	115	-	nA	C
Decrease time	tn tf	tr, tf VR=15V, RL=180Ω –	-	10	200	ns	A
Response time	u', ti		-	10	120	ns	B, C

*2 Applicable divisions correspond to output terminals

^{®3} Current of each segment (At other segments, Anode and Cathode is short-circuited.)

D1		Segment No.	Output
D2	DA	D 1, D 5	
D3	D4	D 2, D 5 D 3, D 5	
D5		D 3, D 3	

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